



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

October 15, 2026

IGI Report Number

DESCRIPTION

SHAPE AND CUTTING STYLE

MEASUREMENTS

GRADING RESULTS

CARAT WEIGHT

COLOR GRADE

CLARITY GRADE

ADDITIONAL GRADING INFORMATION

POLISH

SYMMETRY

FLUORESCENCE

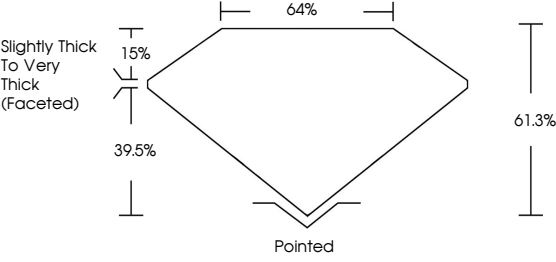
INSCRIPTION(S)

COMMENTS: AS GROWN - NO INDICATION OF POST-GROWTH TREATMENT.
THIS LABORATORY GROWN DIAMOND WAS CREATED BY HIGH PRESSURE HIGH TEMPERATURE (HPHT) GROWTH PROCESS. TYPE II

LG839630404

Report verification at igi.org

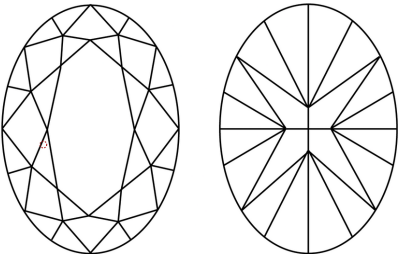
PROPORTIONS





Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL IF VS 1-2 VS 1-2 SI 1-2 I 1-3

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included

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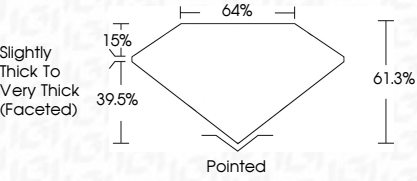
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IGI



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OVAL BRILLIANT

8.89 X 6.43 X 3.94 MM

1.55 CARAT

D

VS 1

61.3%

64%

Slightly Thick To Very Thick (Faceted)

Pointed

EXCELLENT

EXCELLENT

NONE

IGI LG839630404

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